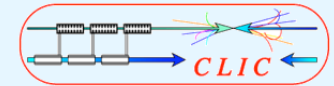


Absorbers Materials for HOM Damping in CLIC PETS and Accelerating Structures

Tatiana Pieloni PSI Zurich and Riccardo Zennaro CERN



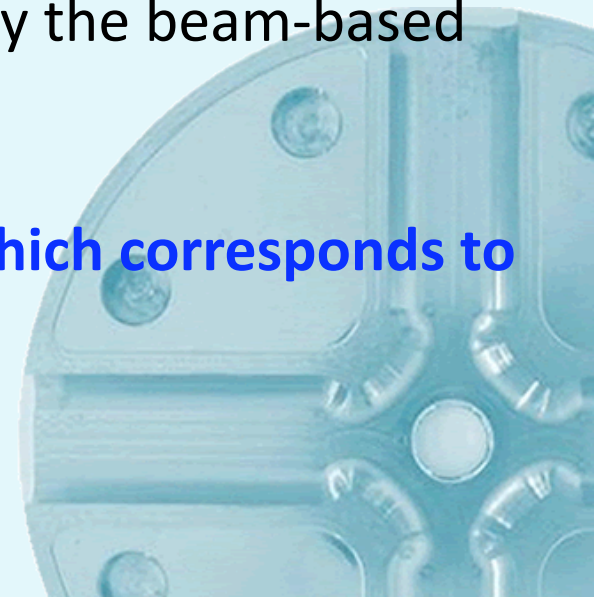


Our Short and medium term Requirements

Find a reliable supply of a reasonable vacuum compatible rf absorbing material with **known and reproducible properties**.

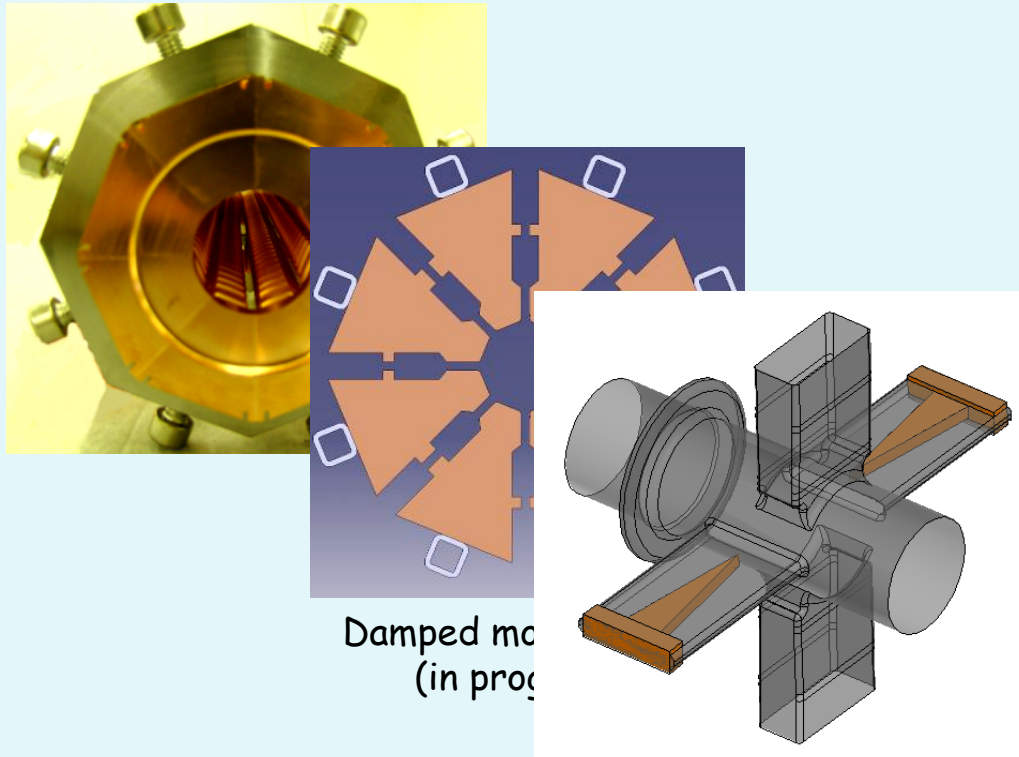
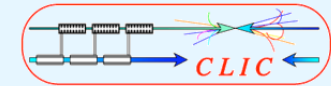
The material will be used by CLIC for load elements in HOM damping features of accelerating structures, PETS and BPMs. These will be tested in klystron based test stands and especially the beam-based TBTS and TBL.

This amounts to at least 30 or 40 structures – which corresponds to thousands of load elements.





Short Term needs: Power Extraction Structures PETS

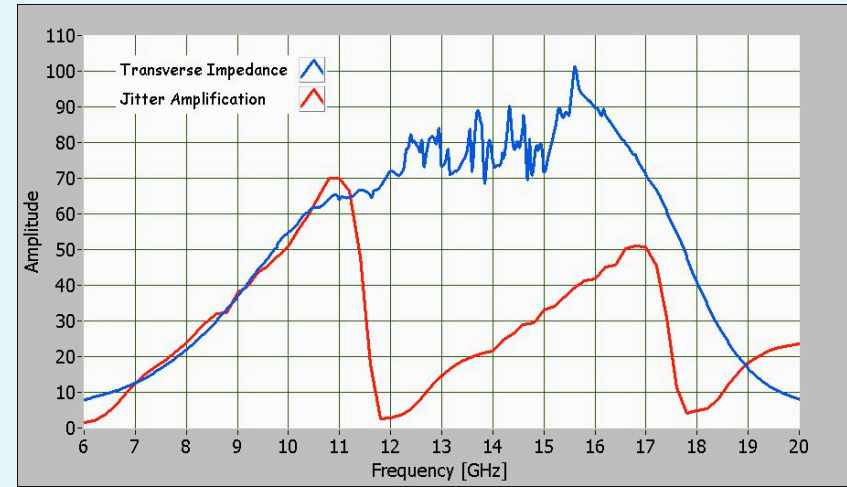


Damped modification
(in progress)

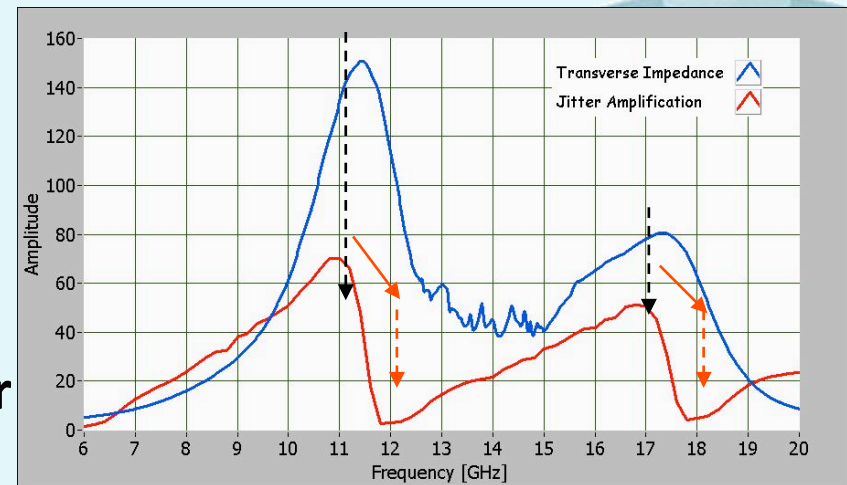
Damped modification
(in progress)

- ϵ in the range of 20 to 30
- loss tangent of at least 0.3
- reproducibility of permittivity of the order of 10% is necessary

Current design:



Fast example of the spectrum modification with 4 loads being switched off:

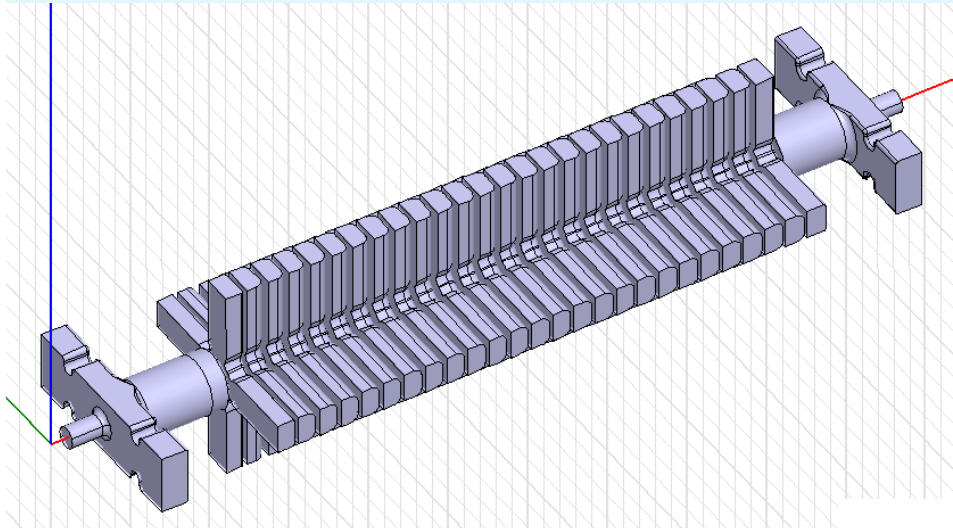
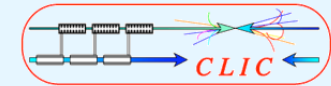


Courtesy of I. Syratchev

HOM FREQUENCY RANGE 10-20 GHz

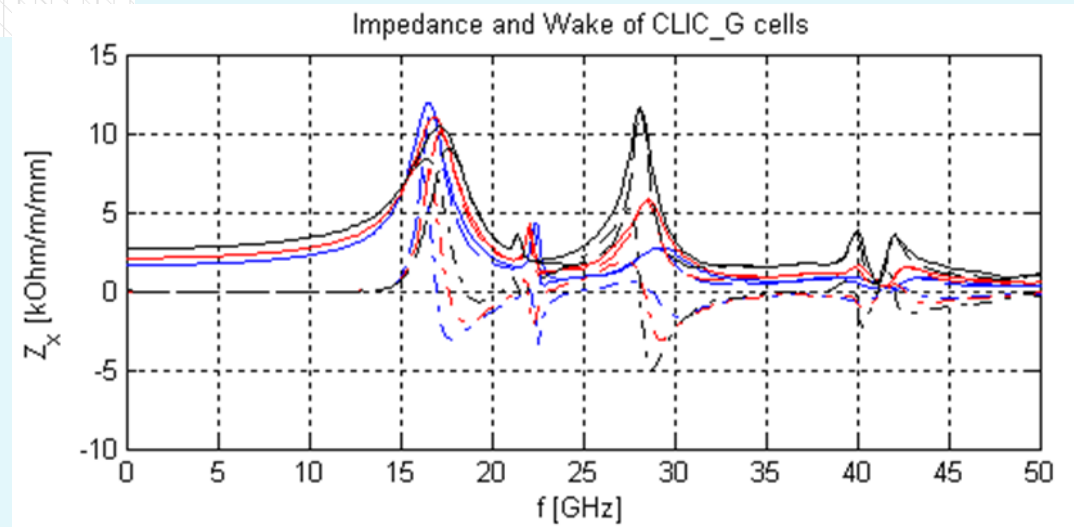
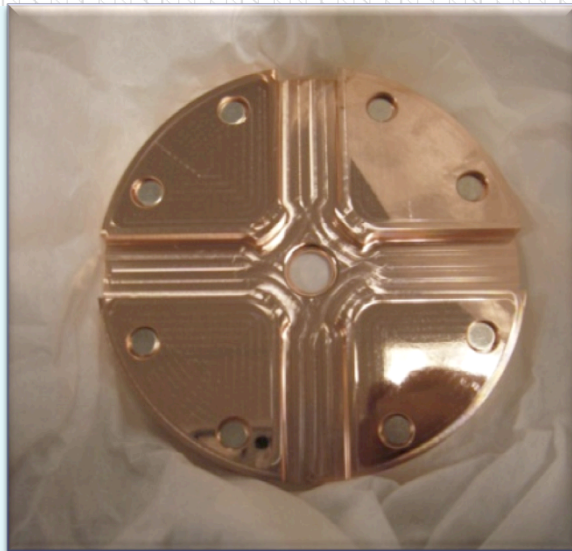


Longer Terms Need: Wave Damped Structure



Waveguide Damped Structure
(WDS) 2 cells

- ϵ_r as low as possible (20 still ok)
- loss tangent of at least 0.3
- reproducibility of permittivity of the order of 10% is necessary

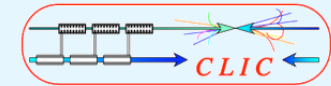


HOM FREQUENCY RANGE 10-45 GHz

Courtesy of A. Grudiev



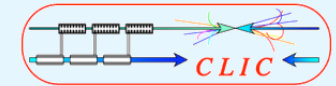
Historical Overview



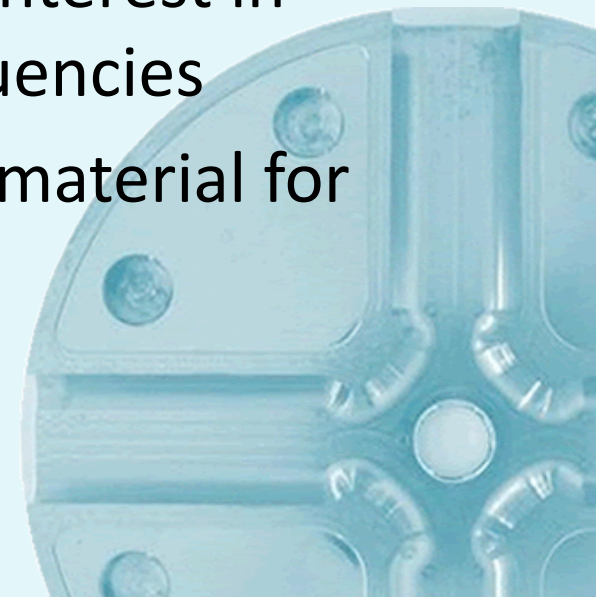
- Work on load elements for CLIC multibunch structures started in 1996. Samples of carbon loaded AlN supplied by R. Campisi
- No supplier was available so switch to SiC 100[®]
- In 1999 successful test of structure, designed by M. Dehler, in ASSET which had 600 SiC load elements. Material also used CTF2 30GHz PETS
- SiC used successfully by E.Jensen in 3GHz SICA structures of the CTF3 main linac. The stability of the linac is some proof that the loads worked.
- By this time Ceramiques&Composites had been bought by ESK and the product line was overhauled. The SiC Erk chose was a version of EKasic, a material intended for mechanical applications. But it worked.
- A few years ago, Erk ordered Ekasic for a 3 GHz dry load development. The measured load performance differed from expected based on previously measured permittivity. Permittivity measurements by R.Fandos of *new* batches gave a (weirdly) high ϵ' of 130 while old batches were just fine.



*Common Interest of many groups to
characterize electromagnetic properties of SiC
and Ceramics in general*

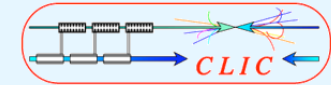


- CIEMAT interest in defining PETS load material
- CERN Collimation Phase II interest in characterizing SiC for possible application
- EPFL-Laboratory of Electro-Magnetism interest in performing measurements at high frequencies
- EPFL -PLASMA group interest in finding material for Gyrotrons





Material Survey CIEMAT

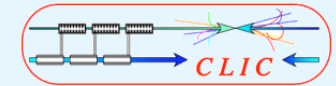


Company	Material	Description	Theoretical Resistivity
Dynamic Ceramic (UK)	SiC	Direct Sintered	$10^2 \Omega\text{cm}$
	Si_3N_4		$10^{10} \Omega\text{cm}$
COORSTEK (USA)	SC-DS	Direct Sintered SiC	$10^5 \Omega\text{cm}$
	SC-RB	Reaction Bonded SiC	$10^3 \Omega\text{cm}$
	SiC HR Grade	Chemical Vapor Depositions	$10^6 \Omega\text{cm}$
ESK (DE)	Ekasic F		$10^6\text{-}10^8 \Omega\text{cm}$
	Ekasic F-Plus		$10^6\text{-}10^8 \Omega\text{cm}$
	Ekasic P		$10^6\text{-}10^8 \Omega\text{cm}$
	Ekasic S		$>10^{11} \Omega\text{cm}$
SAINT GOBAIN	Hexoloy SA SiC 1	Regular Elec. Resistivity	$10^4\text{-}10^6 \Omega\text{cm}$
	Hexoloy SA SiC 2	Higher Elec. Resistivity	$10^7\text{-}10^9 \Omega\text{cm}$
	Hexoloy SA SiC 3	Highest Elec. Resistivity	$10^{10}\text{-}10^{11} \Omega\text{cm}$

Courtesy of L. Sanchez CIEMAT



Material Survey CIEMAT



CERADYNE



EKS



COORSTEK



DYNAMIC CERAMIC

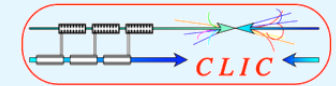


All material samples will be machined and measured

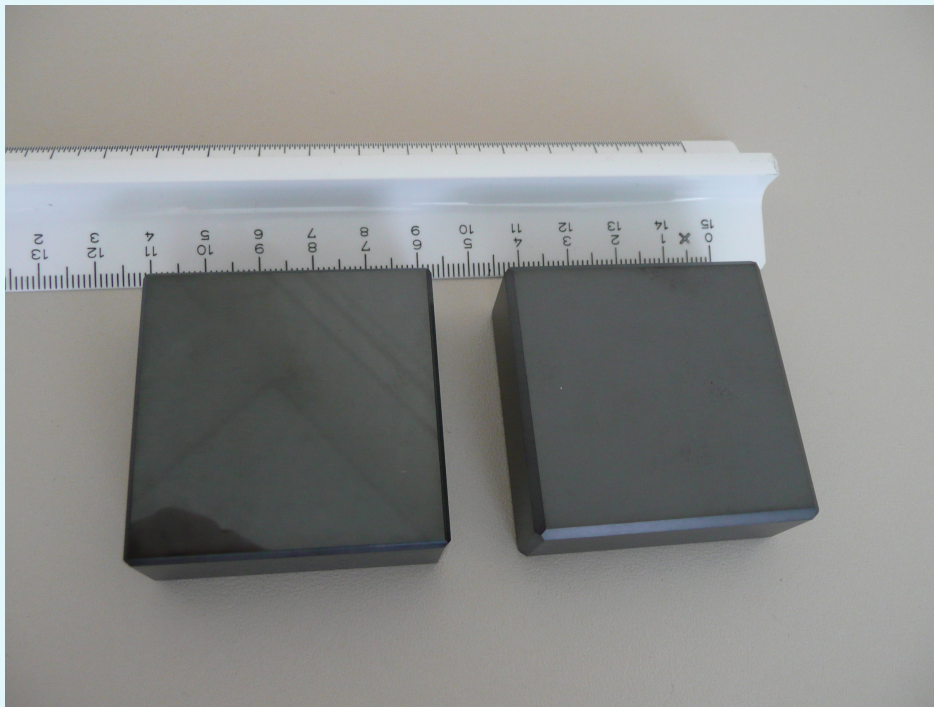
Courtesy of L. Sanchez CIEMAT



KEK Cerasic-B SiC Tiles



Company	Material	Description	Theoretical Resistivity
Covalent Materials Corporation (JP)	Cerasic B	SiC	10^4 - 10^6 Ω cm



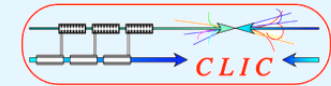
Absorbers material used for KEK



Courtesy of Y. Takeuchi and T. Higo

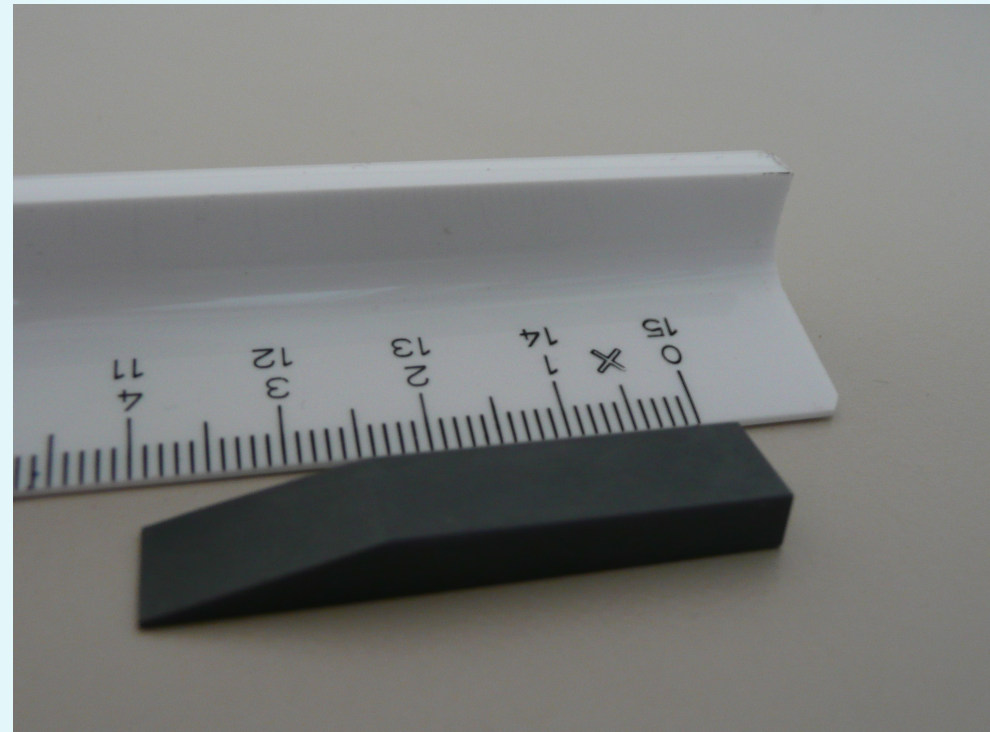


Argonne SiC-AlN sample



Company	Material	Description	Theoretical Resistivity
Ceradyne Inc (USA)	Ceralloy 13740Y	Hot pressed AlN + 40% SiC	$>10^8 \Omega\text{cm}$

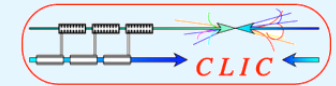
Material currently tested in a 26GHz load at Argonne Nat. Lab.



Courtesy of Chunguang Jing

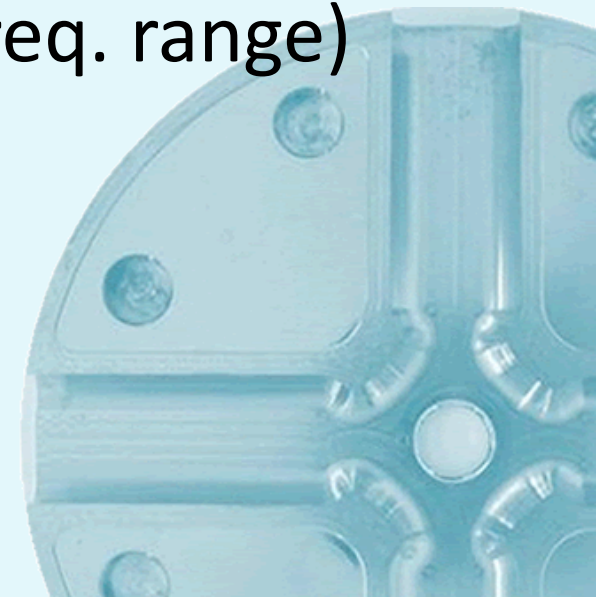


Material Characterization



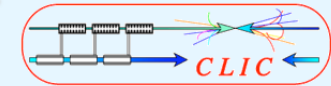
For each Material Sample we want to measure and keep track of:

- Resistivity (in collaboration with Coll. Phase II)
- Complex permittivity (1-50GHz freq. range)





SiC and Ceramics Survey common effort for CLIC RF and for LHC Collimation Phase II



The choice between metallic - ceramic jaw depends on the method of stabilization will be used (LANDAU Damping – Transverse Feedback).

Requirements for Ceramic jaw:

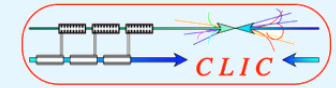
- Electrical resistivity (1-10 Ωm)
- Ceramic tiles bonded on conductive support
- Tile thickness (5-10 mm)
- Gap between tiles (up to 2-3mm)
- Resistivity :1-100 Ωm
- **Diel. Const: as low as possible (up to 5)**
- **Loss factor: < 1E-2**
- Brazability to metal support.
- High density
- High geometrical stability
- High thermal shock resistance

SiC is a promising candidate





Electrical Resistivity Measurements

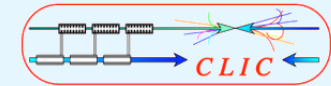


Measurements **constraints** and **solutions**:

- **Contact resistances** between ohmmeter pins and SiC
 - » Four points method
- **Carbon layer** on SiC due to high temperature ($>1100^{\circ}\text{C}$)
 - » Evaporation of Si = graphitization (e.g. during sintering)
 - » Mechanical and thermal surface preparation
- **Photosensitivity** (1 - 5 % of the result)
 - » Measurements must be done at
 - » Regulated temperature and luminosity



Measurements Procedure and Set-up



1. Surface preparation has to be proceeded

Mechanical grinding on each surface of the ceramic to remove the carbon layer

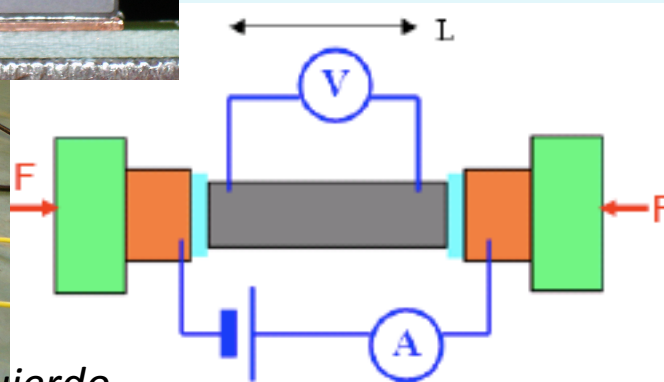
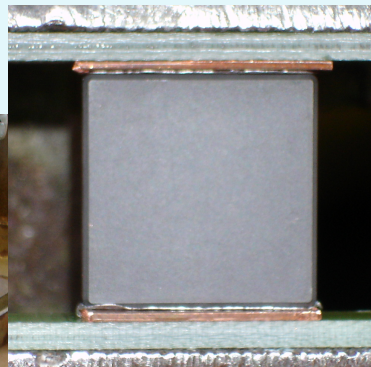
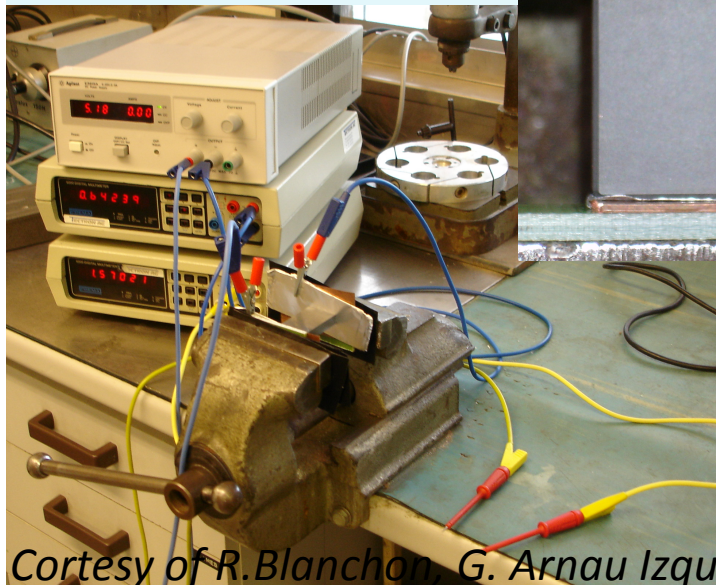
Heat treatment at 1000°C to remove residual impurities

2. Four points method

Injection of current – Measurement of voltage

Calculation of electrical resistivity

$$\rho = R \times \frac{S}{L} \quad R = \frac{U}{I}$$

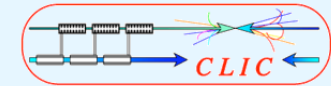


- Voltmeter
- Silicon Carbide
- In or Al sheet
- Copper
- Insulating material
- Current source
- Ammeter

Cortesy of R. Blanchon, G. Arnau Izquierdo



Measurements of CERASIC-B SiC Tiles



- Results on 2 tiles of **CERASIC – B** no surface preparation:

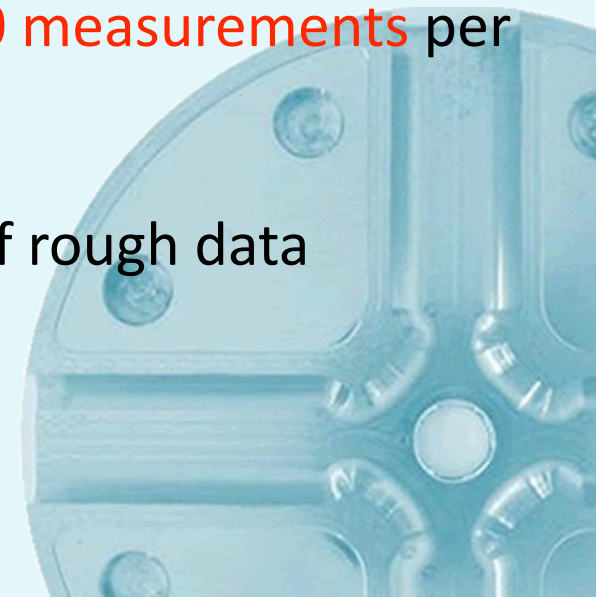
$$\rho_1 = (24071 \pm 3662) \Omega.cm$$

$$\rho_2 = (18772 \pm 3595) \Omega.cm$$

- **Datasheet** from supplier:

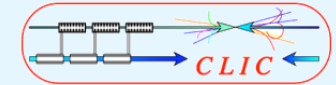
$$\rho_{th} = 10^4 - 10^5 \Omega.cm$$

- These experimental results are an **average of 10 measurements** per tile of SiC.
- **High dispersion** of results → increase number of rough data
 - Several samples for each supplier
 - Measurements on each face of the sample
 - Statistical exploitation of data





Complex Permittivity Measurements



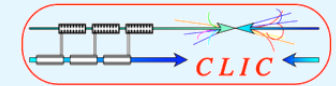
To measure Loss Tangent and Relative Permittivity of Absorber materials in frequency range 1-50 GHz different techniques are under investigation:

- S-parameters measurements for wave guides with material
- Surface and contour plots
- Agilent Dielectric High Performance Probe 85070E 1-50GHz
- EPFL-LEMA laboratory of electromagnetism





S-par Measurements of Material in WG



Wave guides

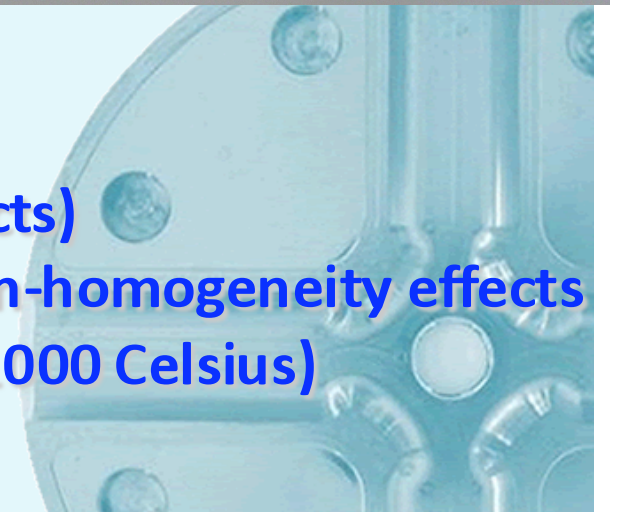
S parameters measurement:

- HFSS + Measurements
(Ref. CLIC-NOTE-766)
- Exploring New analysis method



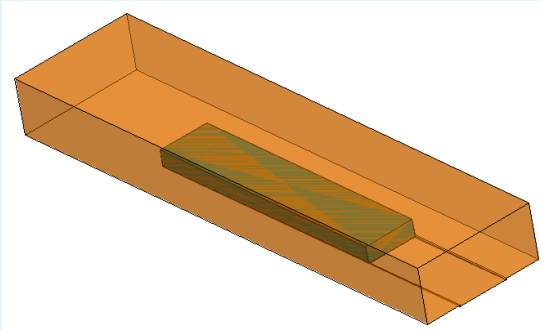
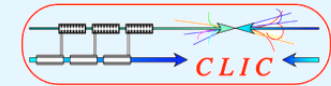
Samples Preparation:

- Machining of samples
 - Different sizes (to define geometry effects)
 - Many samples to have statistics and non-homogeneity effects
- Measurements also after heat treatment (1000 Celsius)





S-par Measurements



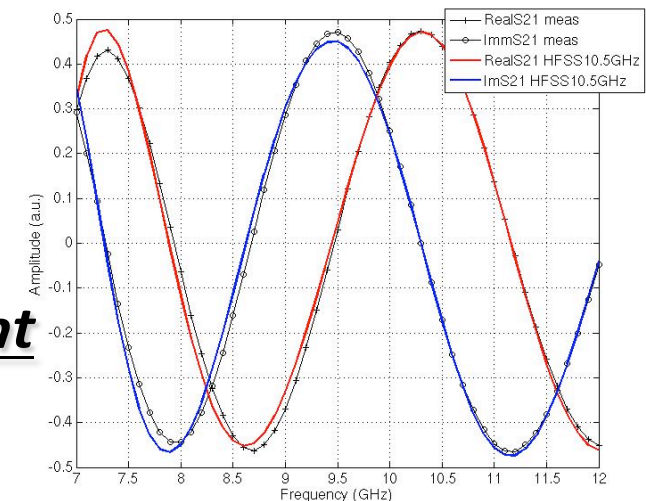
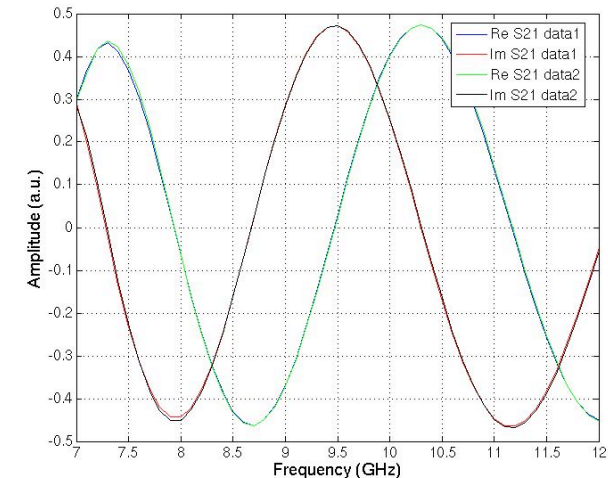
1) Sample in wave guide we **measure S-parameters** with Network Analyzer

2) We **model with HFSS** the measurements with the sample ϵ_r and $tg\delta$ as **free parameters** and we find best values to **match measurements** at different frequencies

3) We define ϵ_r and $tg\delta$ solutions

For this case $\epsilon_r = 11$ and $tg\delta = 0.09$

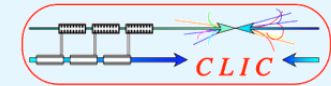
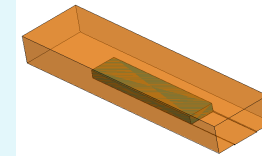
Issues: LONG HFSS RUNS at each measurement and MULTIPLE SOLUTIONS from Optimizer



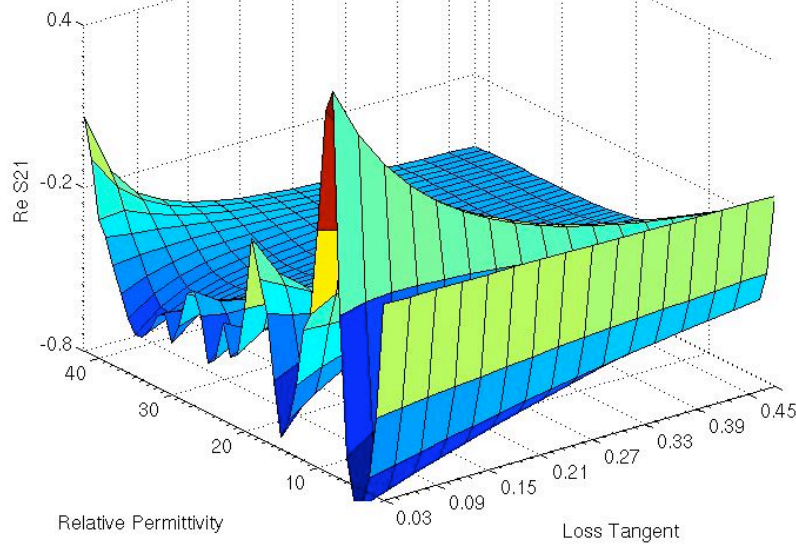
Collaboration for the analysis with CIEMAT D.Carrillo



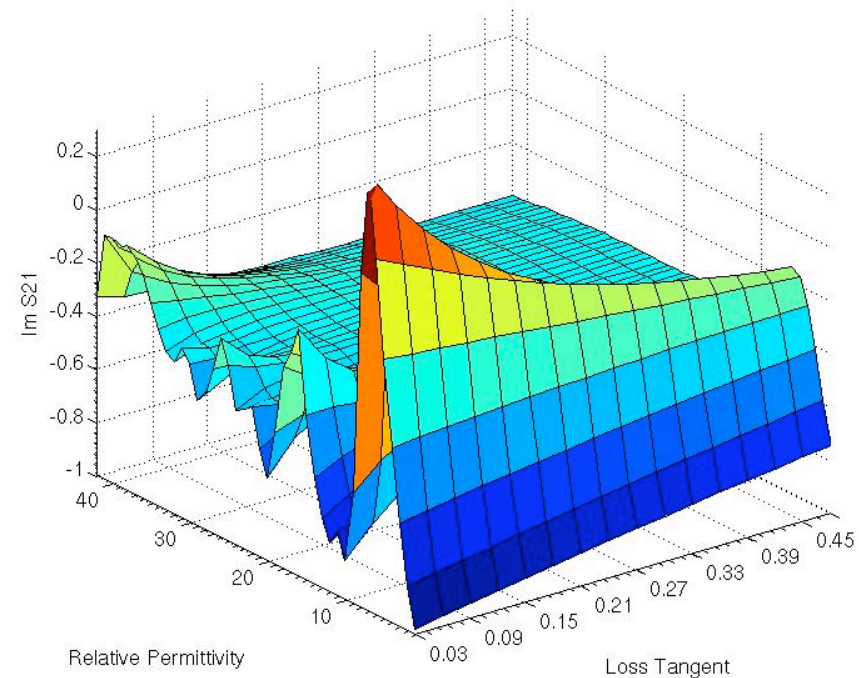
SURFACE METHOD



10GHz case



For defined geometry a scan over all possible values of Loss Tangent and Relative Permittivity we have:
Re and Im S21 and Mag S11



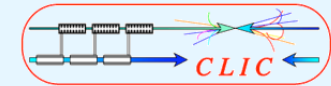
Measured transmission and reflection coefficients define intercepting plane

AT 10GHz $ReS_{21} = -0.178$ and $ImS_{21} = 0.064$
Goals come from measurements

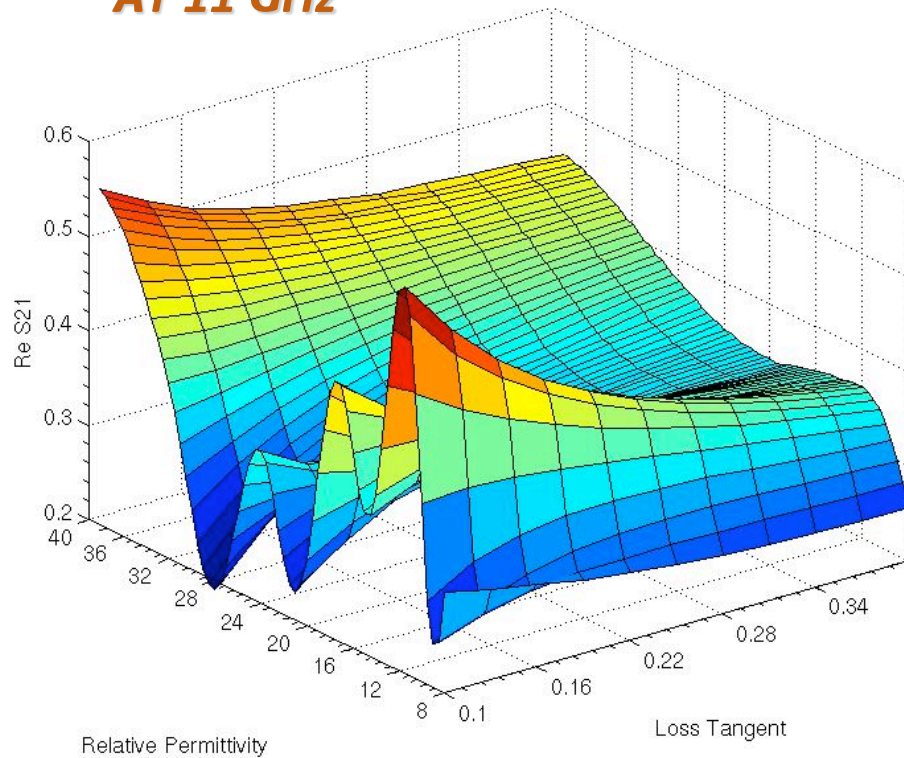




Different materials different measured values



AT 11 GHz



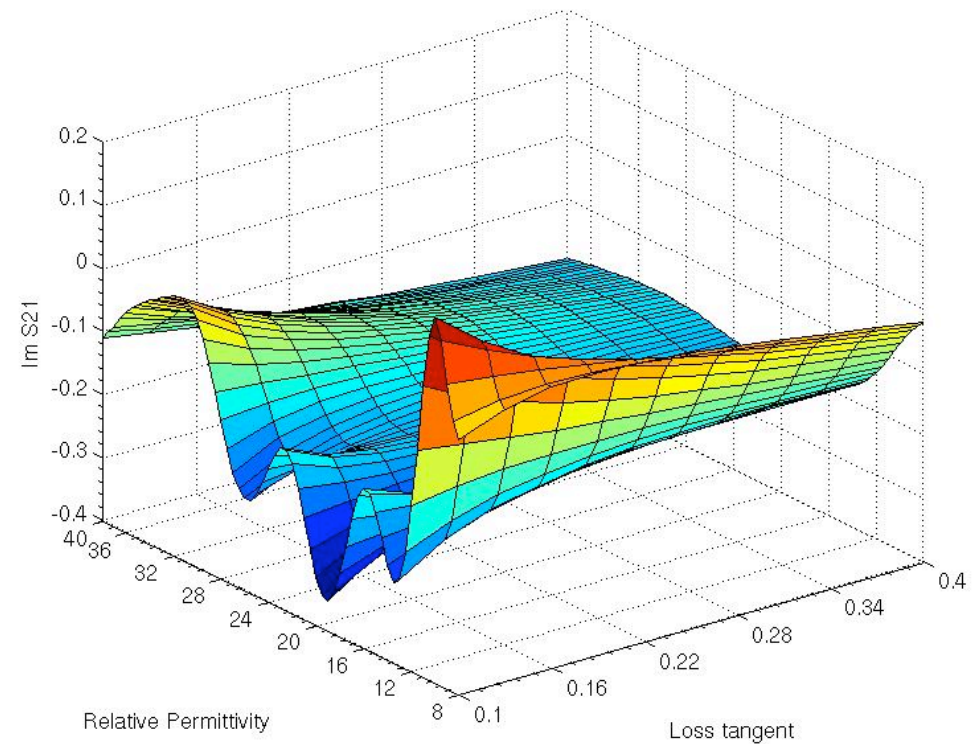
HFSS scan give at a different frequency

Different Re and Im of S21

Measurements give at different freq

Different transmission coefficients

$\text{Re } S_{21} = 0.5$ and $\text{Im } S_{21} = 0.12$

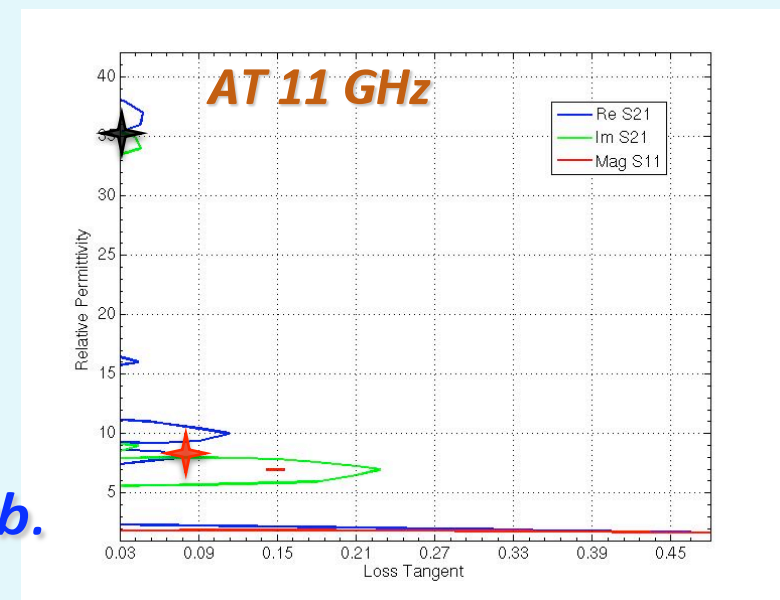
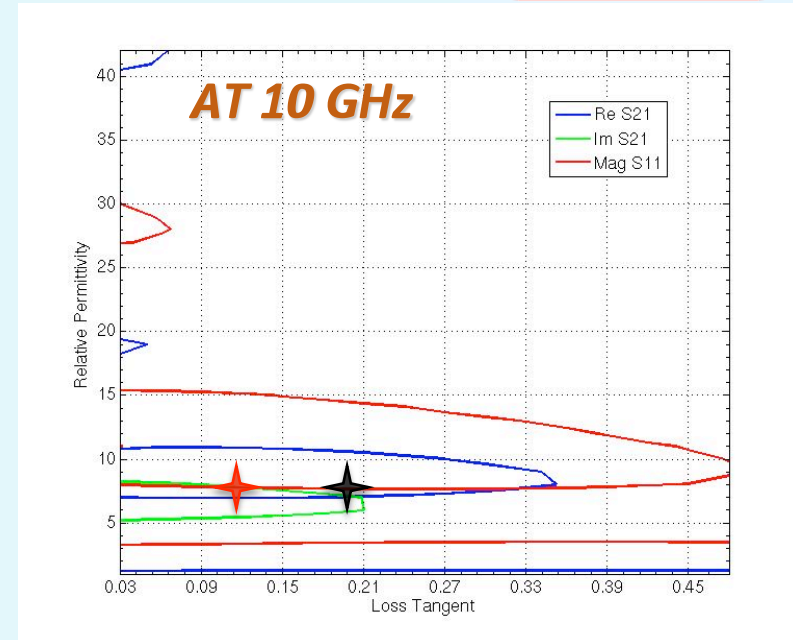
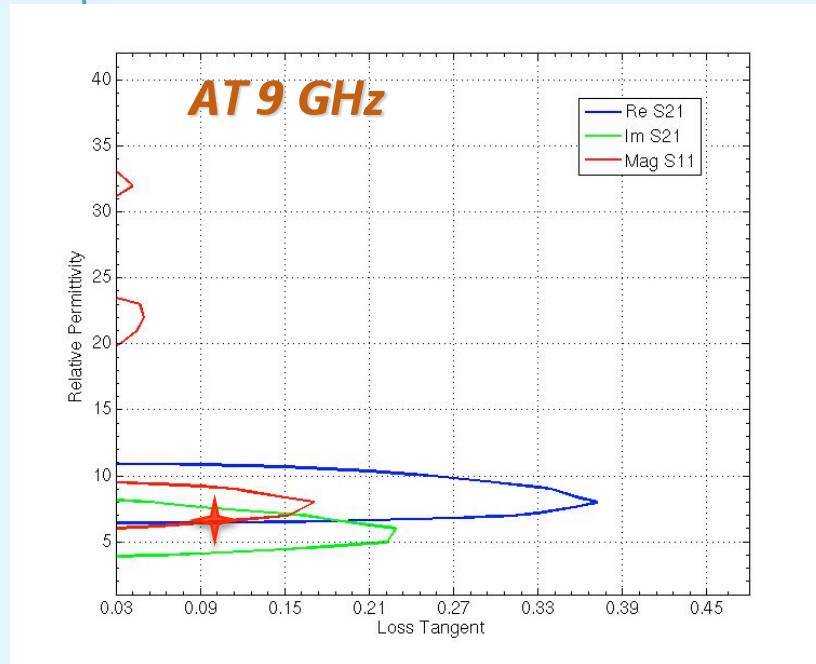
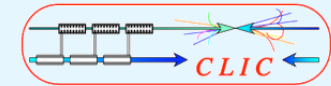


Measurements + simulations

Different Contour Lines



Comparing Contour Plots Physics Result



Measurements + simulations

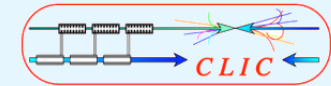
Different Contour Lines

**For this case $\epsilon_r = 11$ and $tg\delta = 0.09$
Is possible solution at all frequencies**

SiC-ALN Material from Argonne Nat. Lab.



News:

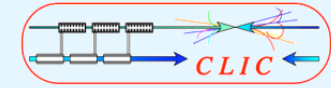


- We found the SiC 100[®] we lost track of, now mainly used for telecommunication applications (telescopes) company changed name: BOOSTEC Inc.
- We ordered samples to verify the material quality and material for PETS loads to be ready for high power test at SLAC
- People from SPS impedance team (Rumolo, Zannini and Salvant) interest in characterizing Ferrites with Wave Guide method

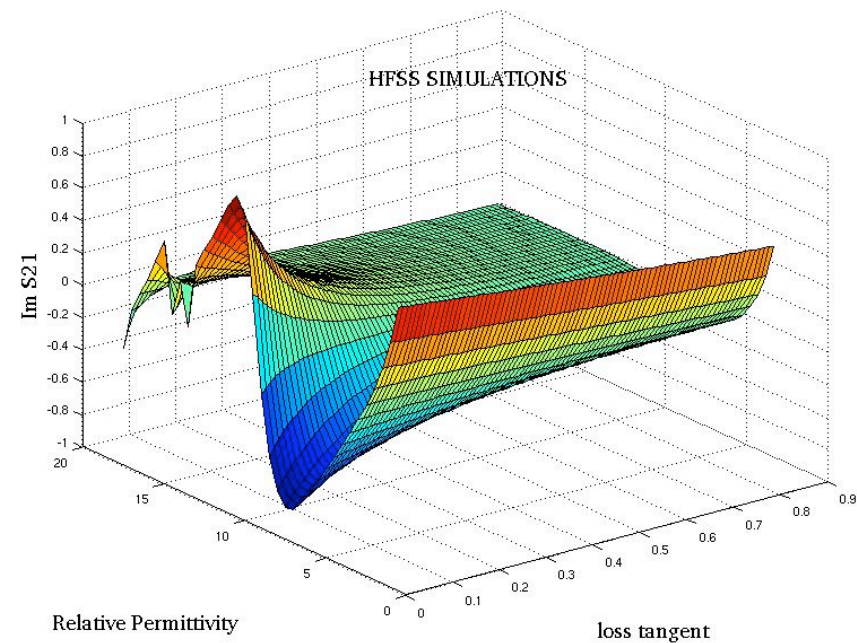
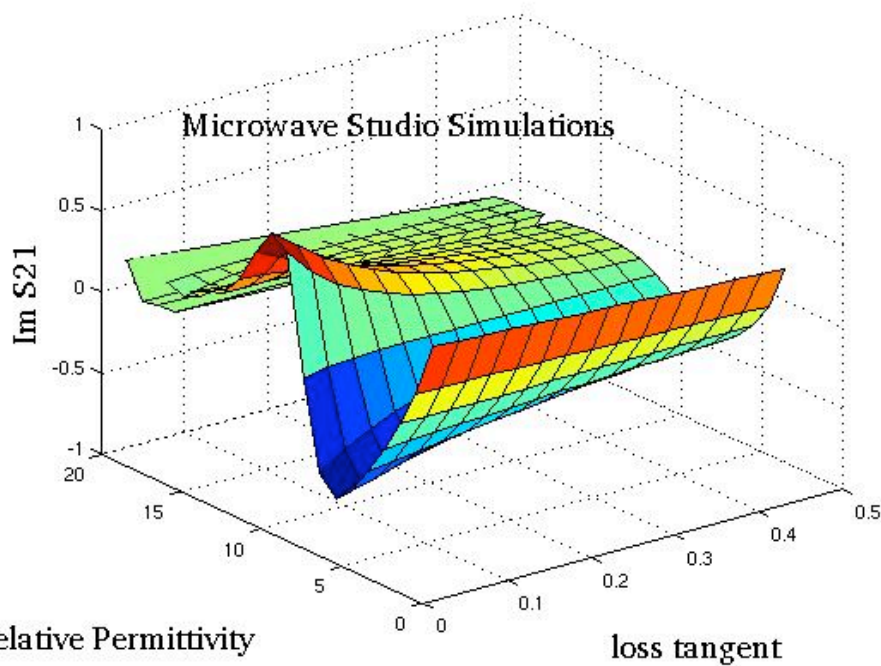




Using Surface and Contour method Comparing Microwave Studio (time domain) and HFSS (frequency domain)



Good Agreement between simulations with HFSS and Microwave Studio

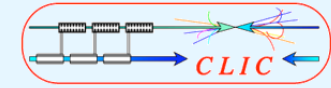


Microwave Studio Simulations: C. Zannini

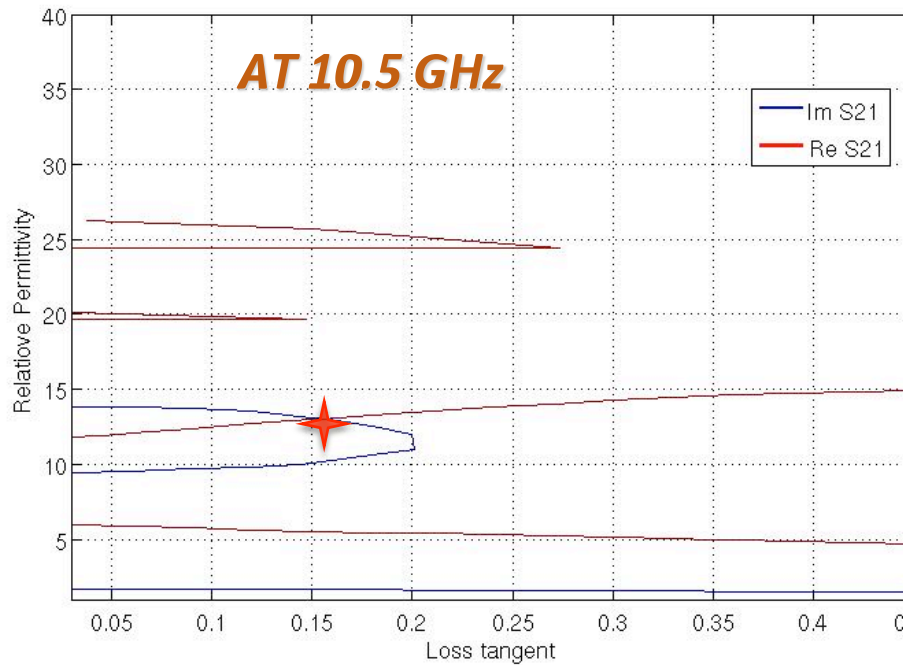
Preliminary results with different steps in loss tangent and relative permittivity



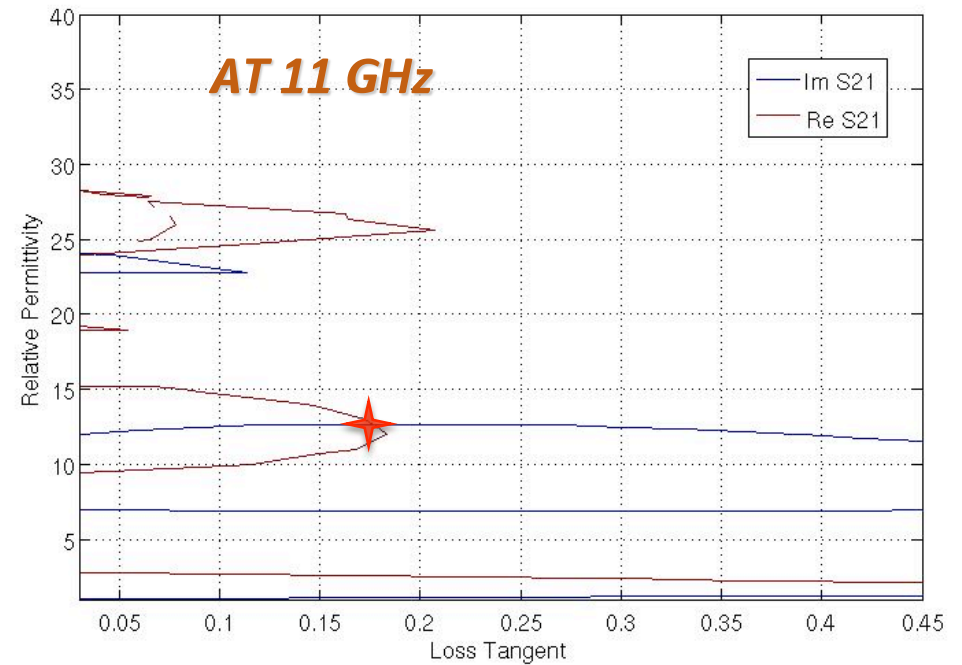
First Measurements [7-12GHz]:



Contour method applied at S21 and measurements on SiC-100 give as follow



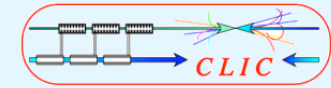
$\epsilon_r = 13$ and $tg\delta = 0.16$



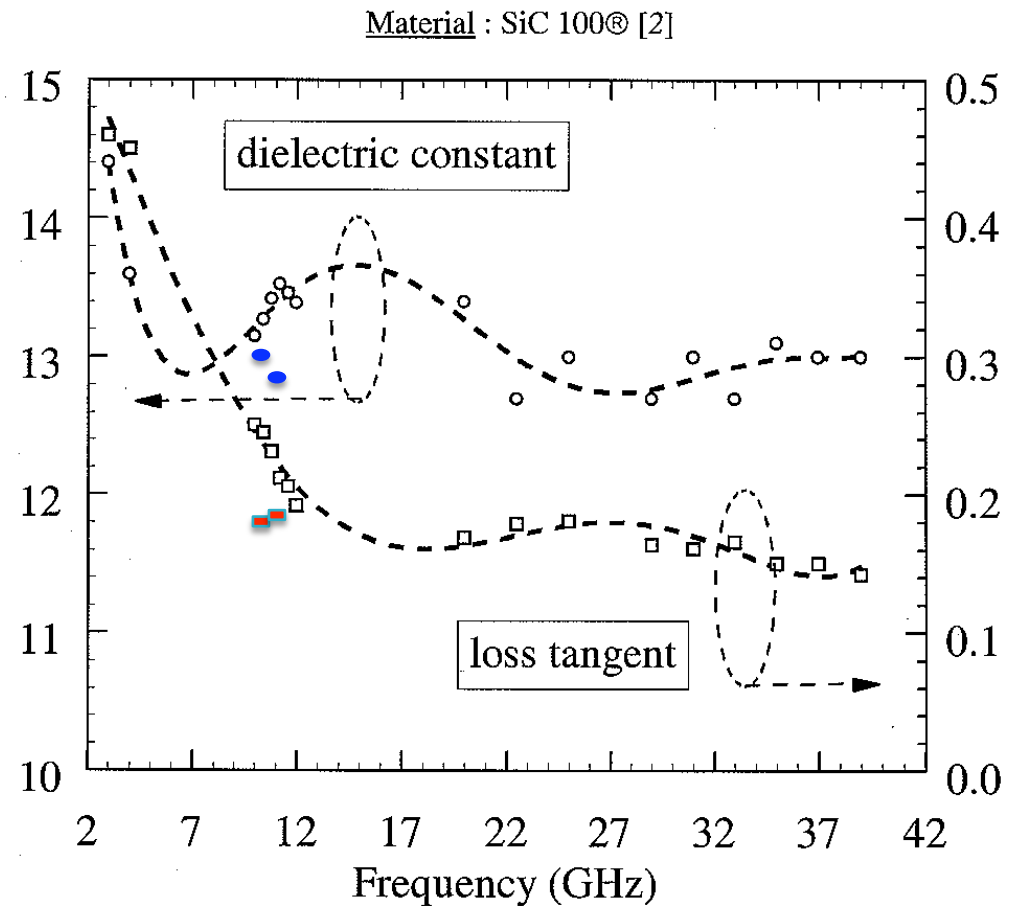
$\epsilon_r = 12.8$ and $tg\delta = 0.175$



SiC-100 from BOOSTEC Inc

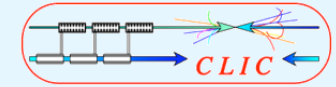


- Microwave Studio (time domain) and HFSS (frequency domain) benchmark give same results
- SiC-100 material today give same relative permittivity and loss tangent as measured by Luong
- Fast Technique to define relative permittivity and loss tangent





Further cross checks at high frequencies for Accelerating Structures

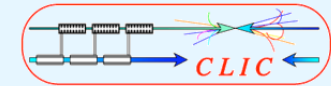


- Higher frequencies with wave guides and surface method
- EPFL – LEMA Group at Lausanne can measure up to 50 GHz complex permittivity of solid materials with different set-ups
- Agilent Inc suggest commercial probe (High Performance Probe) to measure complex permittivity for 0.1MHz-50 GHz





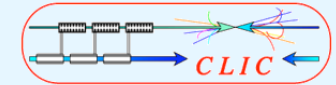
Summary



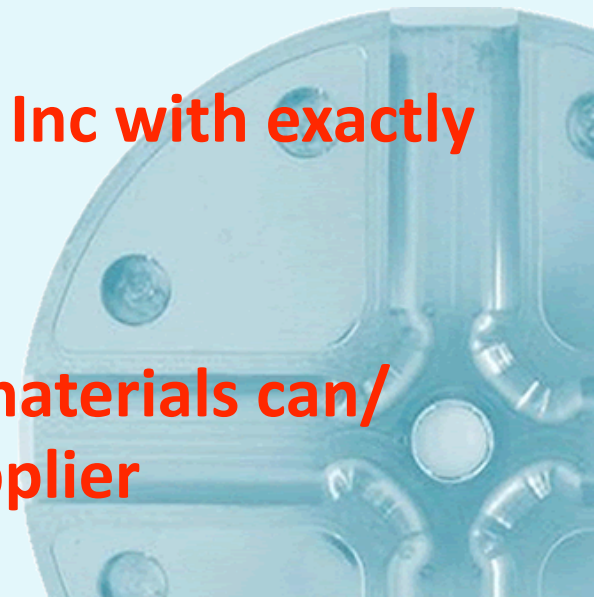
- Material survey have produced large number of promising materials (20 different materials and around 300 pieces to be tested)
- Complete characterization will be performed and data available for future applications of ceramics for loads and ferrite for SPS kickers and PS2 project
- Fast Technique to determine material complex permittivity had been defined using two different simulation models HFSS (frequency domain) and Microwave Studio (time domain)
- Resistivity measurements are part of the material characterization



Conclusions

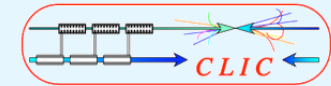


- Permittivity measurements: three different methods applied to keep track of material properties
- Measurements are of interest for different groups (CLIC-RF, SPS impedance team, PS2 and Col. Phase II)
- **SiC-100 still in production at BOOSTEC Inc with exactly same GOOD characteristics as in 1999**
- **Nevertheless defining other suitable materials can/will avoid to depend on one single supplier**





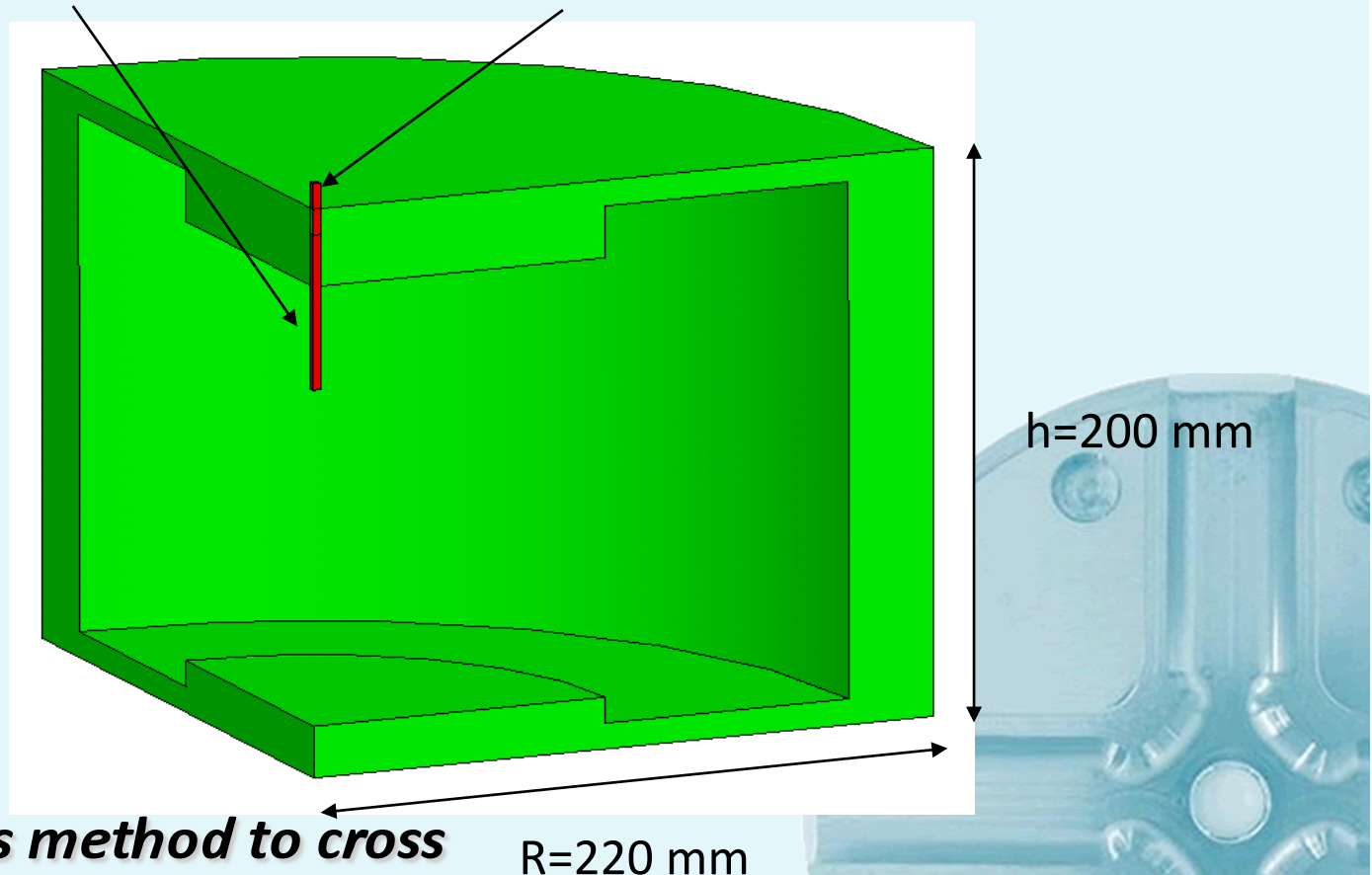
Resonant Cavity Modeling



Preliminary Design of a 500 MHz standing wave cavity TM₀₁ to have information at low frequencies

Dielectric sample, $\varnothing=6\text{mm}$

small aperture in cutoff to insert the sample



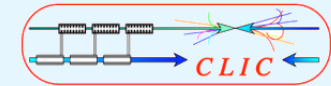
We want to use this method to cross check at some defined frequencies

$R=220\text{ mm}$

$h=200\text{ mm}$

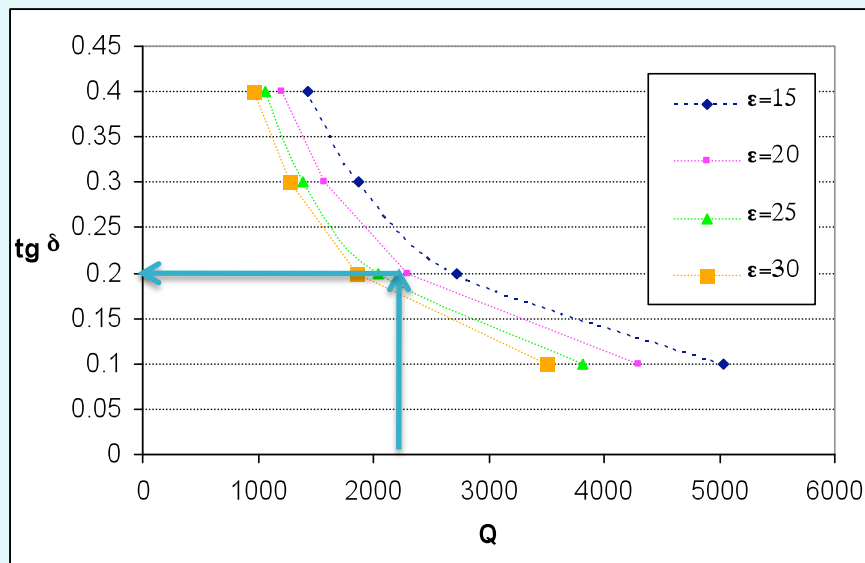
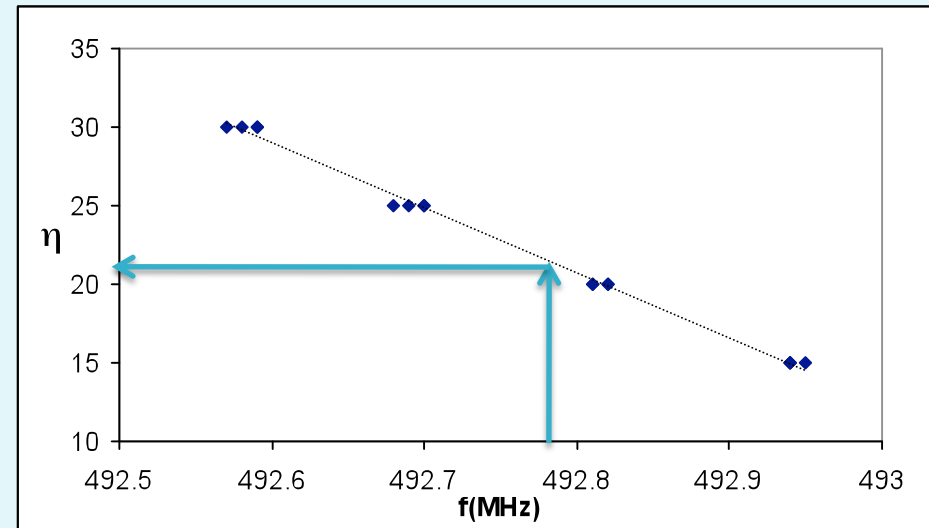


Measurements Procedure and Set-up



**Empty cavity with
Freq 493.40 MHz, $Q=31703$**

**Sweep Relative Permittivity and
Loss Tangent gives
Frequency and Q**

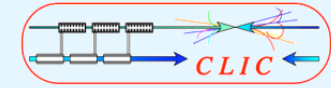


**Measurements will give
Frequency and Q**

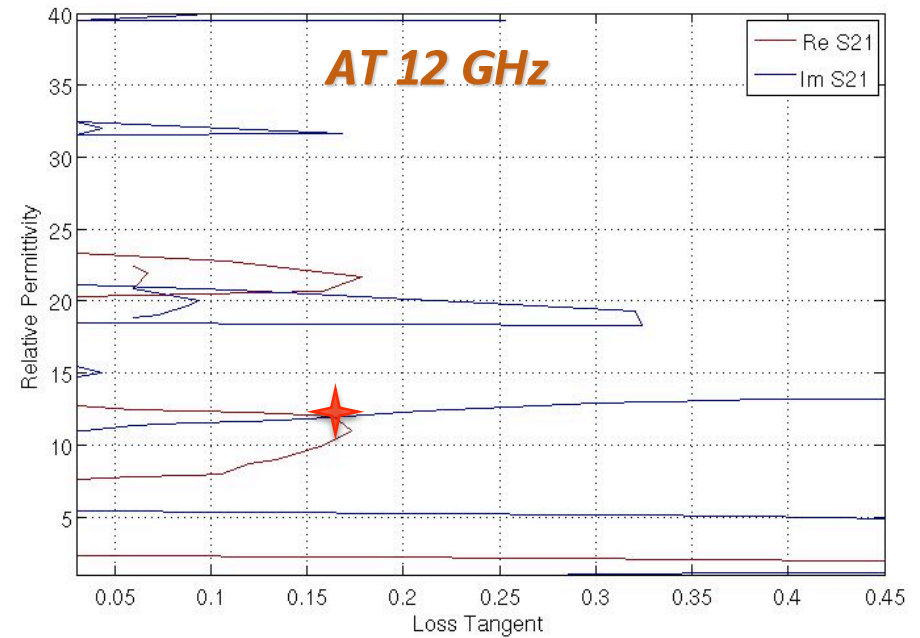
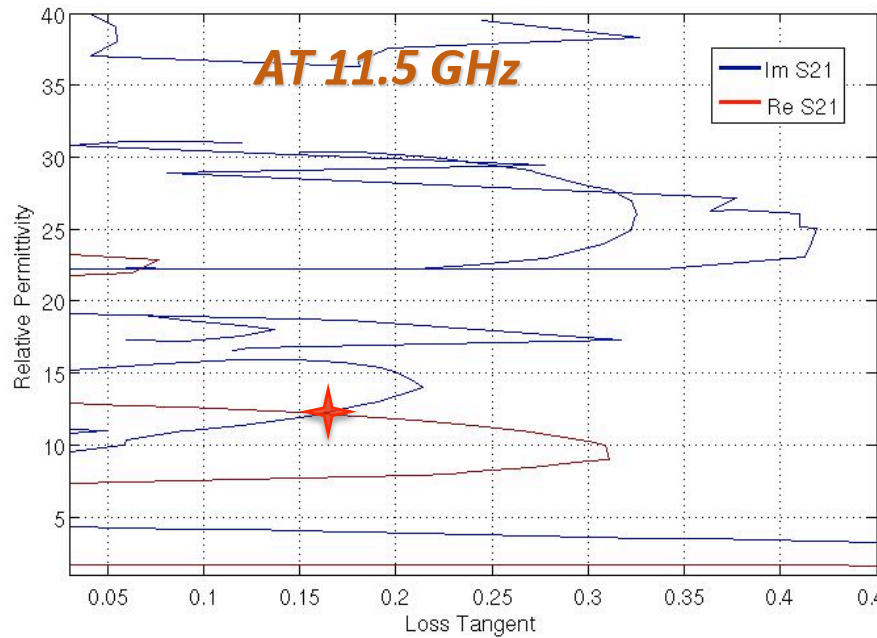
**From sweep and Measurements
Relative Permittivity and
Loss Tangent**



First Measurements [7-12GHz]:



Using Surface and Contour method
Comparing Microwave Studio and HFSS



$\epsilon_r = 12.25$ and $tg\delta = 0.162$

$\epsilon_r = 11.9$ and $tg\delta = 0.164$